H igh-bias stability of m onatom ic chains

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For the m etals Au, Pt and Ir it is possible to form freely suspended m onatom ic chains between bulk electrodes. The atom ic chains sustain very large current densities, but nally fail at high bias. We investigate the breaking m echanism, that involves current-induced heating of the atom ic w ires and electrom igration forces. We nd good agreem ent of the observations for Au based on m odels due to Todorov and cow orkers. The high-bias breaking of atom ic chains for Pt can also be described by the m odels, although here the param eters have not been obtained independently. In the lim it of long chains the breaking voltage decreases inversely proportional to the length.

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I. IN TRODUCTION

As the down-scaling of electronic components is advancing at an impressive rate, the general interest in dissipation and therm al transport at comparable scales is increasing. Technical applications using these sm all scale devices will have higher and higher densities of com ponentsm aking heat generation one of the biggest problem s to overcome. We, therefore, need to develop a better fundam ental understanding of the properties of matter at sm all size scales. A recent review¹ on therm al transport at the nanoscale shows how fast this eld has been growing during the last few years. It also shows that at scales of the order of several nanom eters the quantum behavior of m atter starts to have a m a pr in pact on the therm albehavior of the sam ple. As an exam ple, Yao et al² have shown that the current through a single-wall carbon nanotube is saturating as the voltage reaches values of several volts, a behavior which is not expected from a simple down-scaling of classical e ects.

Here we study the therm albehavior of metals at the smallest length-scales, below 1 nm . A review of results in this eld has recently appeared³. In recent experiments it was shown that som em etals have the property of spontaneously form ing m onatom ic chains just before rupture^{4,5}. A lthough atom ic chains are intrinsically m etastable, experim ents at high bias voltages showed they have a surprising current-carrying capacity⁴, and current densities up to 10^9 A/mm² could be reached. Currently the lengths of these chains is limited to about seven atom s. A better understanding of dissipation and relaxation phenomena may lead the way to fabricate longer chains. W ith these monatom ic chains being nearly ideal onedim ensional conductors this would provide m eans to further study the fundam ental properties of conductors in one dim ension.

In the experim ents described below we probe the stability of m any individual m onatom ic chains by looking at their rate of survival at high bias voltages. A lthough these nanow ires due to their sm all size are ballistic, high bias results in a small probability for inelastic scattering of the electrons to phonons. Energy dissipation has been demonstrated to come into play when eV for the bias voltages applied is raised above the characteristic zone-boundary phonon energy⁶. Energy dissipation will take place on the scale of the electron-phonon scattering length (typically 100 nm), but the num ber of scattering events per volum e will be largest inside the atom ic wire itself due to the large current density. As a consequence the average lattice vibration energy at the narrow est cross-section will be larger than anywhere else in the contact, which can be viewed as an increased locale ective tem perature, $\mathrm{T}_{\mathrm{e}}\,$. This elevated local tem perature can lead to the rupture of the contact and is therefore an im portant param eter.

There have been several experim ental attem pts in m easuring this local e ective temperature inside metallic point contacts, but it has been di cult to obtain quantitative results. Van den Brom et al.⁷ have exploited the switching rate between two di erent con gurations in atom ic sized contacts. W hen the energy barrier between the two con gurations is low enough (which is often found on the verge of an atom ic reconstruction) the local temperature can activate the jumps between the two levels, and the switching rate is determined by the ratio of the elective barrier and the therm all energy. To obtain the e ective tem perature from this switching rate an estim ate of this barrier is required, which is di cult in view of the unknown atom ic con gurations. In order to circum vent this problem the switching rate between the two states was followed while changing the bias voltage and the bath tem perature independently⁸. A com parison between the changes in the switching rates in these two cases would provide a calibration of the relation between the bias voltage and the e ective tem perature. However, the therm al expansion in the electrodes due to the changing temperature changes the atom ic con guration considerably, making it di cult to draw de nite conclusions.

Here we discuss measurements of the fracture rate of

atom ic chains as a function of the voltage bias. The advantage over previous work on T_e in atom ic-sized conductors is that they are free of lattice in perfections and in purities and the structure is known, except for the conguration at the end points. The energy barrier that has to be considered in the process is therefore less com – plex. Moreover, it is possible to consider chains of various lengths, which provides us with a control parameter of the point contact geom etry.

The paper is organized as follows. A fter som e details on the experimental techniques we show in section III that the breaking of an ensemble of chains cannot be described by a simple activated process. W e argue (section IV) that there are a number of parameters involved that lead to a distribution of Boltzm ann factors and we show that the observed distribution in breaking voltages can be fairly well described without adjustable param eters. One of the assumptions, here, is that there is a variation in e ective barriers to breaking as a result of a distribution of tensile forces in the chains. W e verify this assumption in section V by comparison to the measured phonon mode energy in the chains, which re ects the actualtensile force in the monatom ic wire. All experiments to this point were done on gold chains and this is com pared to results for platinum in section VI, which can only be qualitative for lack of data available in the literature. We conclude (section VII) that we have a fairly good description of Joule heating in these atom ic-sized conductors and we obtain a realistic estim ate for the lattice tem perature at nite bias.

II. EXPERIMENTAL TECHNIQUES

The experiments have been performed using the Mechanically Controllable Break Junction (MCBJ) technique⁹. By this technique one breaks a wire of the desired metal in a controlled fashion with the use of a piezo-electric element. The wire is only broken once the sam ple is under vacuum and the tem perature in the vacuum chamber is stable at 42K. Therm al contact to the sample is provided by a copper nger in order to avoid using them alcontact gas. The advantages of the MCBJ technique are, rstly, a large m echanical stability due to the smallmechanical loop connecting the two wire ends. This can be of crucial in portance when one tries to determ ine the stability of m onatom ic chains. Secondly, the cryogenic vacuum without use of therm alexchange gases ascertains the absence of gas molecules in the environm ent that could lead to additional cooling of the contact and contam ination of the metal nanow ire. Our relying on cryogenic vacuum has the disadvantage that we cannot increase the tem perature of the experiment much since this would lead to a deterioration of the vacuum . The gold and platinum wires used here have a purity of at least 99.998% .

Chains of atom s were produced in the following way. During the breaking of the wire by use of the piezo-

elem ent the wire conductance decreases in steps¹⁰, which have been shown to be due to atom ic recon gurations 11 . The last plateau in the conductance, observed just before the conductance suddenly drops to a negligible value and the wire is broken, is generally due to a contact with the cross section of a single atom 12. W hen the length of this plateau exceeds the typical length for a single atom it can be considered as a measure for the length of an atom ic chain being form ed^{4,13}. In order to fabricate atom ic chains of a given length L the process is repeated as long as the contact breaks before the plateau (and chain) reaches the desired length: The two electrodes are pushed together again to reestablish a big contact and a new atom ic contact is pulled out. W hen after several attempts the desired chain-length is reached the piezo m ovem ent is halted and m easurem ents on the properties of the atom ic chain are started. During this procedure the conductance of the atom ic contact is measured using a constant bias voltage of the order of 10 m V.

The e ective length L that we will use as a parameter below refers to the length of the last plateau in the conductance, as was done in previous studies^{4,13}. The length measures the stretching of the contact from the point where the conductance rst drops to the value of a single-atom contact. It is widely accepted that the starting point corresponds to a contact of one atom . D epending on the detailed evolution of the chain a plateau length of L = 0.5 nm for gold would have two or three atoms in a row, and L = 1 nm would have four or ve atom s. Som e recent m odel calculations 14,15 suggest that the structure of the contact at the starting point of a plateau can be viewed as two electrodes ending in a single atom and touching vertex-atom to vertex-atom which would make the chains one atom longer, but this remains to be veri ed experim entally.

III. RATE OF DECAY OF ATOM IC CHAINS

O new ould expect the stability of the m on atom ic chain to be determined by the ratio of the energy barrier against breaking, W , and the e ective tem perature, $T_{\rm e}$. A population, P , of chains would then show an exponential decay as a function of time, t,

$$P(t) = P(0) \exp(t =);$$
 $\frac{1}{f} \exp(W = k_B T_e);$ (1)

where f is the frequency by which the system attempts to overcome the barrier. In estimates and simulations given below we will take $f = 3.5 \qquad 10^{12}$ Hz, a typical phonon frequency for monatom ic gold chains^{6,16}.

In order to investigate this stability by a simple experim ent the decay of a population of m onatom ic gold chains was followed as a function of time. The moment a chain of the desired length is created is taken as t = 0 and the time until the chain spontaneously breaks was stored for a set of consecutively formed chains. The evolution of the number of surviving chains as a function of time, out

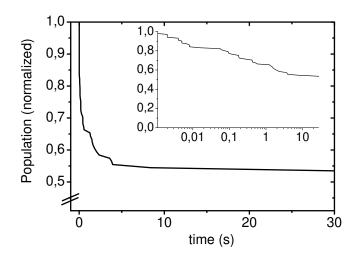


FIG.1: The number of m onatom ic chains remaining intact as a function of time out of an initial population of 100. The inset shows the same data on a logarithm ic time-axis. The results were obtained for m onatom ic gold chains with an effective length of 0.4 nm, at a temperature of 4.2 K and at a constantly applied bias voltage of 200 m V.

of an initial population of 100, is presented in gure 1. C learly, the observed dependence is not described by the expected exponential decay. The inset in gure 1 shows that it actually more closely follows a logarithm. A logarithm can be obtained if we consider for the chains in the population a distribution of barriers, a distribution of e ective tem peratures, or both. Note that the characteristic time for breaking is in uenced by the applied bias voltage, which is 200 mV in the exam ple of gure 1. N ear zero bias the lifetim e of atom ic chains at 4.2 K is m ainly limited by the patience of the experimentalist.

IV. A DISTRIBUTION OF BOLTZMANN FACTORS

The distribution of lifetim es for given e ective length L observed in gure 1 may result from a variation in the energy barrier W of the chain, which is likely due to variation in the tensile force. From the fact that a chain will always break when the tensile force exerted is large enough, one can conclude that the e ective barrier height m ust decrease with force. As shown by the force m easurem ents on m onatom ic chains perform ed by R ubio et al.¹¹ the force varies strongly while pulling to form a chain, and will sensitively depend on the atom ic con gurations at the connection points to the banks. A ssum ing a dom inant low est order (linear) term the barrier energy can be written as

$$W = W_0 \quad j V j \quad j F j; \qquad (2)$$

where W $_0$ is the equilibrium barrier energy. We have also included a linear decrease of the barrier due to electromigration upon application of a bias voltage V. This

term is motivated by model calculations by Todorov et al.^{17,18} U sing a single-orbital tight-binding model they have shown that the barrier against breaking reduces linearly with voltages up to 1V. More recent calculations based on density functional theory by B randbyge et al.¹⁹ have shown that the electrom igration force can be highly non-linear. How ever, form any con gurations it will be a reasonable approximation.

A part from a variation in the energy barrier we should also consider the locale ective tem perature at the point contact. For vanishing bias voltages the elective tem – perature approaches the bath tem perature, T_0 . Beyond a certain threshold voltage it should rise due to a voltage-driven term, T_V . Following reference 17 we describe the locale ective tem perature of the atom ic contact as:

$$T_{e} = (T_{0}^{4} + T_{v}^{4})^{1=4} :$$
 (3)

An estimate for the dependence of $T_{\rm V}\,$ on voltage can be obtained from an earlier paper by Todorov²⁰. Three terms are included in the estimate: (1) Heating by the electrons due to creation of phonons in the atom ic w ire, (2) the cooling by the electrons due to absorbtion of phonons, and (3) cooling by the therm altransport of energy away from the point contact into the metal banks. If only the st two terms are included the temperature is simply proportional to the voltage, $k_B T_e$ ' eV, where it has been assumed that electrons exchange at most a single quantum of vibration energy. Note that recent experim ental work by Zhitenev et al.²¹ on m olecular junctions indicates that several vibrational quanta can be deposited per electron. However, this e ect can be attributed to the relatively long residing times of the electrons inside the molecular bridge²². Earlier experimentalwork on phonon spectroscopy in monatom ic gold chains shows that multiple phonon scattering is negligibly sm all for these ballistic wires, in agreem ent with the assumption by Todorov.

An elective temperature $k_B\,T_e$ 'eV would correspond to thousands of Kelvins at commonly employed bias voltages. However, the third term, the therm alconduction to the banks, limits the heating considerably. It is more dicult to make precise estimates, but when the behavior of the banks is taken to follow the bulk heat conduction and heat capacity we obtain²⁰

$$T_{V} = \frac{p}{L \sqrt{y}}$$
(4)

where is a proportionality constant given as = 60 K V $^{1=2} \text{ nm}$ $^{1=2} \text{ and } \text{L}$ is the length of the chain. This was qualitatively con rm ed by an independent approach by Chen et al²³.

In order to investigate experim entally the e ect of bias voltage heating on the stability of the chains, taking a distribution of w ire properties into account, we proceeded as follows. First chains of the desired length are produced following the procedure described above. This is done at a bias voltage of 10 mV, a value which is below the typical electron-phonon excitation energy⁶. This

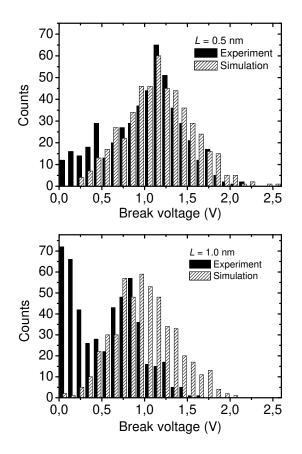


FIG.2: A distribution of the number of gold atom ic chains as a function of bias voltage at which they were observed to break. The upper panel shows the experimental and simulated result for 500 chains with L = 0.5 nm long at a tem perature of 4.2 K, while the lower panel shows similar data for chains of L = 1.0 nm long.

ensures that the e ective tem perature in the point contact will remain close to the bath temperature. Once a chain has been form ed we wait for 1 s to see whether the chain is indeed stable. Next, the voltage is ram ped with a constant speed of about 1V/s until the chain breaks. The bias voltage at breaking is stored and it is reset to 10 m V. The electrodes are then pushed together again to repeat the experiment for the next chain. The results for such an experiment are represented in gure 2. The top panel shows a histogram constructed from the m easured bias voltages at breaking for a set of 500 gold atom ic chains with L = 0.5 nm. The distribution clearly peaksat12V with a fullwidth at halfm axim um of 0.6V. The lower panel shows a similar set of experimental results for chains of L = 1.0 nm in length. In this case we observe two peaks in the distribution, one at low bias representing a large fraction of chains that break early, and a second peak at 0.8V. A possible dependence on the voltage ram p speeds was not investigated, but earlier work found negligible in uence of this parameter in atom ic contacts²⁴.

We have suggested above that the breaking of the

atom ic chains can be described as a therm ally activated process. However, for this we need to verify that the energy barrier is not signi cantly modied by therm al expansion due to the rising of the local e ective tem perature at high bias voltage. In a test we measured two sets of 500 atom ic chains. With the rst set the bias voltage was suddenly increased from 15 to 800 m V once the chains had been form ed. A large number of chains was seen to break following a similar logarithm ic time dependence as displayed in gure 1.W ith the second set we suddenly dropped the voltage from 300 to 50m V after which we observed not a single chain breaking. Note that a higher bias should lead to therm al expansion of the electrodes²⁵ and thus to a sm aller tensile stress than at low bias. These two tests show that the in uence of the therm al expansion on the energy barrier, if present, is dom inated by the therm ally activated breaking.

In order to compare the results of gure 2 with the proposed model for the variation of the energy barrier and e ective tem perature on bias voltage we need realistic estimates for the constants in equation 2. We adopt the values $W_0 = 0.738 \text{ eV}$ and = 0.14 eV/V obtained in reference 17 from a non-equilibrium tight-binding calculation for a gold atom ic chain. The value for in equation 2 can be estim ated from the results by Rubio et al¹¹ They found that gold atom ic chains typically break at a tensile force of 1.5 nN. At the point of breaking the lifetime, , of a chain has been reduced to the experimentaltime scale, which is 0:1 s in the experim ents of reference 11. The locale ective tem perature at the point contact will be given by the bath tem perature in view of the low bias voltage of 10 m V used in these experiments. For = $0:1 \text{ s and } T_e = T_0 = 4.2 \text{ K}$ we obtain from equation 1 an average barrier of 0.011 eV at breaking. The barrier of 0.738 eV therefore nearly vanishes under the in uence of a tensile force of 1.5 nN, resulting in a value of = $0:49 \, \text{eV} / \text{nN}$.

Wewill now see whether the combination of these values give a reasonable description of the experim ental results of gure 2. W e assume here that the only m issing, i.e. not m easured, param eter is the tensile force. The average tensile force on an atom ic chain can be estimated qure 1 in reference 11 to be 0:95 0:15nN.We from performed a numerical simulation of these data based on equations 1 to 4 and using a norm aldistribution of forces with a mean value of 0.95 nN and a standard deviation of 0.15 nN, which produces the distribution presented in gure 2. The peak position and width agree very well with those observed in the experim ent. Note that all param eters have been obtained from independent m odel calculations and experim ental data, so that there are no adjustable parameters. For an elective length L = 1 nm (low er panel) the peak in the num erical sim ulation is slightly higher than observed. A more signi cant disagreem ent is in the width of the distribution, which is about twice as large in the num erical result, and also the peak at zero bias rem ains unexplained. Nevertheless, the qualitatively agreem ent obtained using literature values

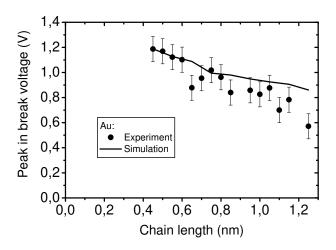


FIG. 3: Position of the maximum in the distribution of breaking voltages (gure 2) for monatom ic gold chains as a function of their e ective length. The bullets represent the experimental results obtained by tting a Gaussian curve to each population form ed by 500 chains. The curve is a numerical simulation, as described in the text.

for the param eters suggests that we have at least captured some of the physics involved. Thus, this analysis suggests that the broad distribution in breaking voltages ism ainly caused by the large distribution of tensile forces in an ensemble of atom ic chains. The processes leading to the relatively unstable chains breaking at very low voltages is unclear as of yet. A possible explanation would be a large portion of chains quickly breaking when the bias voltage reaches the threshold value of the low est phonon m ode in the point contact.

In order to follow the length dependence in more detail we have constructed histogram s sim ilar to the ones shown in gure 2 form any chain-lengths. From the histogram s we extract the position of the maximum of the distribution at nite bias and plot this as a function of length. This dependence is depicted in gure 3 and show s that the average breaking voltage decreases from 1.2V at L = 0.45 nm to just below 0.6V at L = 1.25 nm.

W ith the sam evalues for the m odel param eters as used above we obtained the curve shown in gure 3. In view of the fact that there are no free param eters the agreem ent between the m odel and experim ent is surprisingly good, although the values at greater length dem onstrate a larger deviation. The reason for the deviation m ay be in the m odel or the choice of param eters. How ever, one aspect that we have ignored and that should become e im portant for longer chains is the contribution of the entropy. The larger num ber of bonds present in longer chains will reduce the e ective barrier²⁶.

V. TEST OF THE VARIATION IN TENSILE FORCES

In order to test whether the width in the experim ental distribution at higher bias voltages is the result of a variation in the tensile forces one would like to be able to measure the forces in the point contact. The MCBJ in its original con guration is not suitable to determ ine these, but it is possible to obtain som e inform ation in an indirect way using Point Contact Spectroscopy $(PCS)^{27}$. By this technique one probes the di erential conductance dI=dV as a function of voltage using a sm allm odulation superim posed on the dc bias ram p. As soon as the excess energy, eV, of the electrons shooting through the point contact becom es larger than the energy of a phonon m ode inside the contact a new channel for back-scattering sets in resulting in a sudden reduction of the conductance. This technique was applied to atom ic contacts by Untiedt et al.²⁸ and to monatom ic gold chains by Agra tet al⁶, who showed that the observed phonon energy decreases when the tensile force on the chain is increased. This is as intuitively expected: A s the tensile force F increases the distance between the atom s a in the chain increases leading to a weakerbond and a lowerstiness = dF = da. Since the observed longitudinal phonon mode energy is proportional to the phonon frequency changes accordingly.

Wemakeuse of this e ect in the following experiment. First we produce a chain of the desired length via the procedure described above. Next, a point contact spectrum is recorded by m easuring the di erential conductance as a function of bias voltage in the interval between -50 and + 50m V, using a lock-in amplier. Som e chains are lost during this procedure due to an increase of the e ective tem perature caused by the increased bias voltage. W hen this happens the data are discarded and a new chain is form ed. A fler having m easured the di erential conductance the bias voltage is ram ped up sim ilar as in the previous experim ent, at a rate of 1V/s. The data are stored and analyzed after collecting a large set of curves. For all point contact spectra that show a clear phonon signal the phonon frequency can be compared to the breaking voltage. The data are then sorted according to the observed phonon frequencies and collected in bins of 1 m eV wide. For the data within each bin the average breaking voltage and its standard deviation are evaluated.

Figure 4 shows the average breaking voltage as a function of the observed phonon frequencies, where the error bars on each data point represent the standard deviation. For a sm all fraction of about 2% of the spectra m ore than one phonon frequency could be identied, and these were not taken into account in gure 4. The break voltage in the graph clearly rises as a function of phonon energy, just as is expected. For a higher phonon frequency the force constant is higher and the chain is expected to be less strained, and thus the energy barrier to breaking is higher. The distribution of breaking voltages at each phonon energy is still quite broad. From this ob-

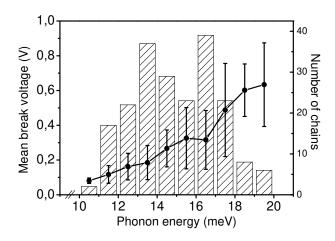


FIG. 4: A verage breaking voltage of gold chains with an e ective length of 0.9 nm as a function of the observed phonon frequency (bullets). The bars indicate the number of data points used to obtain the average (right axis). The standard deviation in the break voltage for each phonon frequency is represented by the size of the error bar.

servation one can conclude that the tensile force indeed plays the expected role on the stability, but that there are still other param eters that in uence the survival rate of atom ic chains at high bias voltage. Such param eters could be variations in the shape of the leads giving rise to di erences in therm al conduction and e ective tem peratures. A lso, various atom ic con gurations of the leads at the connection points to the chain m ay give rise to different equilibrium values for the barrier at zero voltage and zero strain, W_0 . This m ay also lead to a variation in the dependence of the barrier on bias voltage via electrom igration forces.

VI. PLATINUM

Gold is not unique in form ing atom ic chains and it is now known that this property is shared with Pt and Ir^{29} . In contrast to Au, Pt is a metal with both a signi cant density of s and of d-electrons at the Ferm i energy. The behavior for Pt could therefore deviate from the results predicted by the model presented above, since the theory was largely based on the single-orbital tight-binding studies by Todorov et al¹⁷.

The inset of gure 5 shows a histogram of breaking voltages for 500 Pt atom ic chains, measured by the same method as gure 2 for Au. Since the conductance for Pt single atom contacts or monatom ic chains is not as sharply de ned near a quantum unit of conductance as is the case for Au the length of the atom ic chain is less obviously de ned. This problem was discussed and successfully addressed in reference 29 and we employ the same approach for determining the elective chain length. Al-though the results in gure 5 are largely similar to those obtained for Au they diler in some respects. First, for

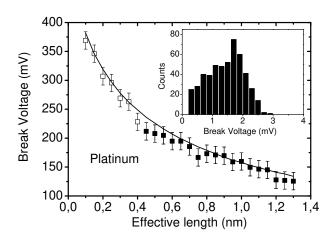


FIG.5: The main panel shows the evolution of the maximum in the distribution of breaking voltages (illustrated for 500 chains of length L = 1.0 nm in the inset) for Pt atom ic chains as a function of length. Filled squares show the data points that are in the same interval as measured for Au in gure 3; open squares represent data points outside this interval. The full curve shows the result of the model calculation described in the text.

an e ective length of L = 1.0 nm the position of the m aximum is now located at 0.17 V, much lower than found for Au, while the width of 0.12 V is only slightly sm aller. A lso, the fraction of chains breaking at very low currents is signi cantly sm aller.

Just as for Au one can follow the position of the maxin um in the breaking currents as a function of length. Such a graph is presented in gure 5, where the led data points represent data in the same length interval that was also measured for Au, while the open symbols are at sm aller lengths. This is to emphasize that the differences in behavior are less dram atic than a com parison of the two gures may suggest. The rapid rise towards smaller lengths may not be unique for Pt. We would like to use again equations 2 through 4 to describe the experin ental results for the breaking voltage as a function of length. However, in contrast to Au most parameters in the model cannot be found in the literature. Therefore, we take a slightly di erent approach and start from the assumption that all chains break as soon as their mean lifetime becomes of the order of the characteristic experim entaltim e-scale. W e further assume that the e ective tem perature at breaking is much larger than the bath tem perature, so that T_e ' T_V . Combining equations 2 { 4 we obtain

$$= \frac{1}{f} \exp \left(\frac{W_{\rm F}}{k_{\rm B}} \frac{j V j}{L j V j} \right); \qquad (5)$$

where W $_{\rm F}$ = W $_0$ hF ji represents the barrier against breaking averaged over a distribution of forces. We set

equal to an experimental time scale of 10m s, but the choice a ects the results only logarithm ically. Taking $W_F = 0.23 \,\text{eV}$, (note, this is W_0 reduced by the averaged

strain) = 200 KV $^{1=2}$ nm $^{1=2}$ and = 0.39 eV/V, a set of values which is within reasonable limits, the resulting curve shown in gure 5 describes the experimental data quite well. This set of values is not unique as can be seen from inspection of equation 5: the values of , and W $_{\rm F}$ can be scaled by an arbitrary constant. Yet, we can nd reasonable values for the constants and obtain a good qualitative description of the data using the same m odel as for Au above. For L ! 0 the break voltage assumes a value W $_{\rm F}$ = while for large L the break voltage decreases as 1=L, but is expected to saturate when eV approaches the characteristic phonon energies of the chain.

VII. CONCLUSIONS

W e have studied m onatom ic chains for Au and Pt and nd a system atic dependence of the characteristic chainbreaking voltage vs the chain length. A tom ic chains sustain surprisingly large current densities, but the maximum current (or voltage) decreases as the chain length grows. W e have adopted a model proposed by Todorov and cow orkers and nd a satisfactory agreement with the observations. Especially for gold the agreement is surprisingly good in view of the fact that we have not used any adjustable parameter. Yet, there are deviations that are not captured by the model and that require further study. For Pt the general behavior of the average breaking voltage as a function of length can also be closely described by the model, although the parameters have not been independently verified. The agreement obtained inspires condence in equations 3 and 4 and we can now estimate the elective (lattice) temperature inside the atom ic wire. It rises proportional to the square root of of the bias voltage for su ciently large bias and for a monatom ic gold chain of length L = 1 nm at V = 1V it reaches a temperature of 60 K, which is well above the bath temperature of 42 K.

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